# 74HC4017; 74HCT4017

# Johnson decade counter with 10 decoded outputs Rev. 4 — 10 December 2013 Produ

**Product data sheet** 

#### 1. **General description**

The 74HC4017; 74HCT4017 is a 5-stage Johnson decade counter with 10 decoded outputs (Q0 to Q9), an output from the most significant flip-flop (Q5-9), two clock inputs (CP0 and CP1) and an overriding asynchronous master reset input (MR). The counter is advanced by either a LOW-to-HIGH transition at CP0 while CP1 is LOW or a HIGH-to-LOW transition at  $\overline{\text{CP}}1$  while CP0 is HIGH. When cascading counters, the  $\overline{\text{Q}}5-9$ output, which is LOW while the counter is in states 5, 6, 7, 8 and 9, can be used to drive the CP0 input of the next counter. A HIGH on MR resets the counter to zero (Q0 =  $\overline{Q}$ 5-9 = HIGH; Q1 to Q9 = LOW) independent of the clock inputs (CP0 and CP1). Automatic code correction of the counter is provided by an internal circuit: following any illegal code the counter returns to a proper counting mode within 11 clock pulses. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V<sub>CC</sub>.

#### 2. **Features and benefits**

- Wide supply voltage range from 2.0 V to 6.0 V
- Input levels:
  - ◆ For 74HC4017: CMOS level
  - For 74HCT4017: TTL level
- Complies with JEDEC standard no. 7 A
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

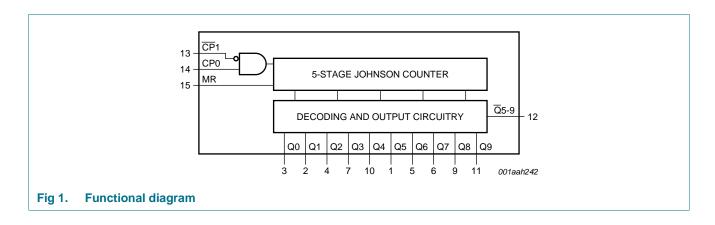


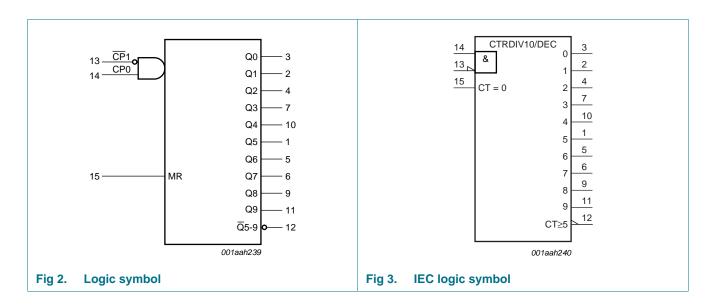
# 3. Ordering information

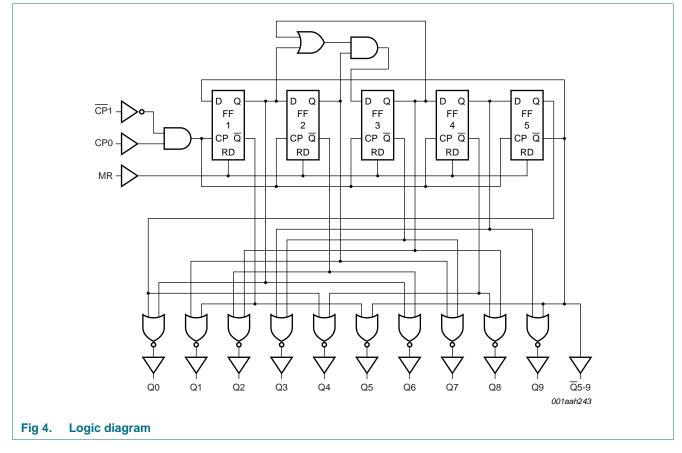
Table 1. Ordering information

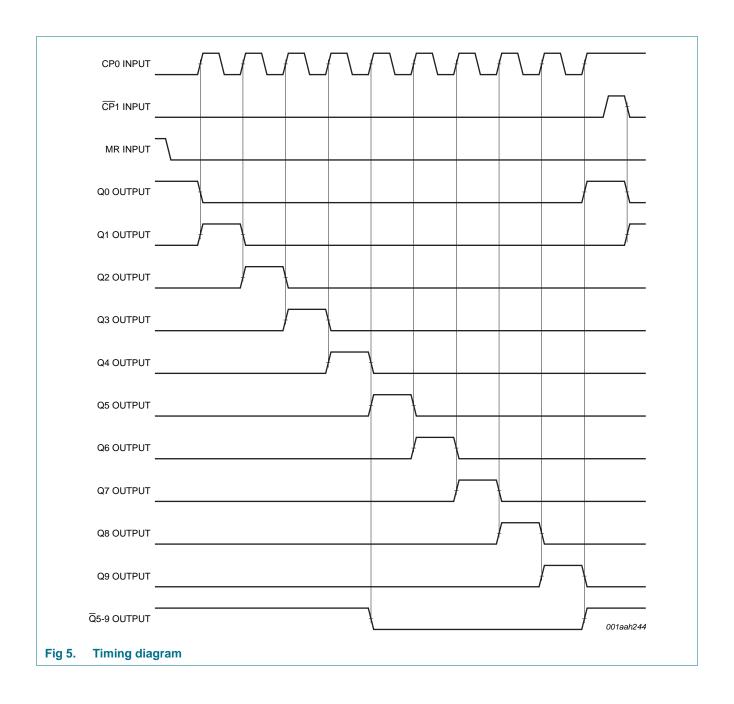
Type number	Package			
	Temperature range	Name	Description	Version
74HC4017				
74HC4017N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HC4017D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HC4017DB	–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1
74HC4017PW	–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
74HC4017BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced very thin quad flat package; no leads; 16 terminals; body $2.5\times3.5\times0.85$ mm	SOT763-1
74HCT4017				
74HCT4017N	–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
74HCT4017D	–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74HCT4017BQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal-enhanced very thin quad flat package; no leads; 16 terminals; body $2.5\times3.5\times0.85$ mm	SOT763-1

# 4. Functional diagram



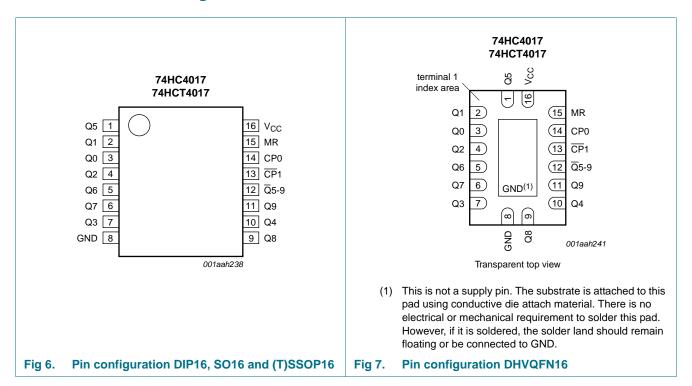






# 5. Pinning information

# 5.1 Pinning



# 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q[0:9]	3, 2, 4, 7, 10, 1, 5, 6, 9, 11	decoded output
GND	8	ground (0 V)
<del>Q</del> 5-9	12	carry output (active LOW)
CP1	13	clock input (HIGH-to-LOW edge-triggered)
CP0	14	clock input (LOW-to-HIGH edge-triggered)
MR	15	master reset input (active HIGH)
$V_{CC}$	16	supply voltage

# 6. Functional description

Table 3. Function table[1]

MR	CP0	CP1	Operation
Н	X	X	Q0 = $\overline{Q}$ 5-9 = HIGH; Q1 to Q9 = LOW
L	Н	<b>↓</b>	counter advances
L	<b>↑</b>	L	counter advances
L	L	X	no change
L	X	Н	no change
L	Н	<b>↑</b>	no change
L	<b>\</b>	L	no change

<sup>[1]</sup> H = HIGH voltage level;

# 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> _	±20	mA
Io	output current	$-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			
	DIP16 package		[2] _	750	mW
	SO16 package		[3] _	500	mW
	(T)SSOP16 package		[4] _	500	mW
	DHVQFN16 package		<u>[5]</u> _	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

L = LOW voltage level;

X = don't care;

 $<sup>\</sup>uparrow$  = LOW-to-HIGH transition;

 $<sup>\</sup>downarrow$  = HIGH-to-LOW transition;

<sup>[2]</sup>  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

<sup>[3]</sup> P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.

<sup>[4]</sup>  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

<sup>[5]</sup> P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C.

# 8. Recommended operating conditions

Table 5. Recommended operating conditions

	<u> </u>					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
74HC4017						
V <sub>CC</sub>	supply voltage		2.0	5.0	6.0	V
V <sub>I</sub>	input voltage		0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	V
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 2.0 \text{ V}$	-	-	625	ns/V
		$V_{CC} = 4.5 \text{ V}$	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	ns/V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
74HCT4017						
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
VI	input voltage		0	-	$V_{CC}$	V
Vo	output voltage		0	-	$V_{CC}$	V
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 4.5 V	-	1.67	139	ns/V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C

# 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		–40 °C to	+85 °C	–40 °C to +125 °C		Unit
				Тур	Max	Min	Max	Min	Max	
74HC40	17					'				
$V_{IH}$	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V
$V_{OH}$	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	5.9	-	5.9	-	V
		$I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	3.84	-	3.7	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	5.34	-	5.2	-	V

**Table 6.** Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C		-40 °C t	o +85 °C	–40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$			ı	ı	1	1		
	output voltage	$I_O = 20 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	-	0.33	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT4	017									
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	1.6	-	2.0	-	2.0	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	1.2	8.0	-	0.8	-	0.8	V
$V_{OH}$	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = -20 \mu A$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4 \text{ mA}$	3.98	4.32	-	3.84	-	3.7	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	$I_O = 20 \mu A$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}$	-	0.15	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1.0	-	±1.0	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5$ V; $I_O = 0$ A	-	-	8.0	-	80	-	160	μΑ
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V};$ other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$								
		CP0 input	-	25	90	-	113	-	123	μΑ
		CP1 input	-	40	144	-	180	-	196	μΑ
		MR input	-	50	180	-	225	-	245	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

# 10. Dynamic characteristics

Table 7. Dynamic characteristics

 $GND = 0 \text{ V; } t_r = t_f = 6 \text{ ns; } C_L = 50 \text{ pF; see } Figure 11.$ 

Symbol	Parameter	Conditions			25 °C		-40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
74HC401	17		,								'
t <sub>pd</sub>	propagation delay	CP0 to Qn; CP0 to $\overline{Q}$ 5-9; see Figure 10	[1]								
		V <sub>CC</sub> = 2.0 V		-	63	230	-	290	-	345	ns
		V <sub>CC</sub> = 4.5 V		-	23	46	-	58	-	69	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$ $\overline{\text{CP1}}$ to Qn; $\overline{\text{CP1}}$ to $\overline{\text{Q5-9}}$ ; see Figure 10		-	18	39	-	49	-	59	ns
		V <sub>CC</sub> = 2.0 V		-	61	250	-	315	-	375	ns
		V <sub>CC</sub> = 4.5 V		-	22	50	-	63	-	75	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	20	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH to LOW propagation	V <sub>CC</sub> = 6.0 V MR to Q[1:9]; see <u>Figure 10</u>		-	18	43	-	54	-	64	ns
	delay	V <sub>CC</sub> = 2.0 V		_	52	230	-	290	-	345	ns
		V <sub>CC</sub> = 4.5 V		-	19	46	-	58	-	69	ns
		V <sub>CC</sub> = 6.0 V		-	15	39	-	49	-	59	ns
t <sub>PLH</sub>	LOW to HIGH propagation	MR to Q5-9, Q0; see Figure 10									
	delay	V <sub>CC</sub> = 2.0 V		-	55	230	-	290	-	345	ns
		V <sub>CC</sub> = 4.5 V		-	20	46	-	58	-	69	ns
		$V_{CC} = 6.0 \text{ V}$		-	16	39	-	49	-	59	ns
t <sub>t</sub>	transition time	see Figure 10	[2]								
		V <sub>CC</sub> = 2.0 V		-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V		-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V		-	6	13	-	16	-	19	ns
t <sub>W</sub>	pulse width	CP0 and CP1 (HIGH or LOW); see Figure 9									
		$V_{CC} = 2.0 \text{ V}$		80	17	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V		16	6	-	20	-	24	-	ns
		$V_{CC} = 6.0 \text{ V}$		14	5	-	17	-	20	-	ns
		MR (HIGH); see Figure 9									
		V <sub>CC</sub> = 2.0 V		80	19	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V		16	7	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V		14	6	-	17		20		ns

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**Table 7. Dynamic characteristics** ...continued GND = 0 V;  $t_r = t_f = 6$  ns;  $C_l = 50$  pF; see Figure 11.

Symbol	Parameter	Conditions			25 °C		–40 °C to	+85 °C	-40 °C to	+125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
t <sub>su</sub>	set-up time	CP1 to CP0; CP0 to CP1; see Figure 8									
		$V_{CC} = 2.0 \text{ V}$		50	-8	-	65	-	75	-	ns
		$V_{CC} = 4.5 \text{ V}$		10	-3	-	13	-	15	-	ns
		$V_{CC} = 6.0 \text{ V}$		9	-2	-	11	-	13	-	ns
t <sub>h</sub>	hold time	CP1 to CP0; CP0 to CP1; see Figure 8									
		$V_{CC} = 2.0 \text{ V}$		50	17	-	65	-	75	-	ns
		$V_{CC} = 4.5 V$		10	6	-	13	-	15	-	ns
		$V_{CC} = 6.0 \text{ V}$		9	5	-	11	-	13	-	ns
t <sub>rec</sub>	recovery time	MR to <u>CP</u> 0 and MR to <u>CP</u> 1; see <u>Figure 9</u>									
		$V_{CC} = 2.0 \text{ V}$		5	-17	-	5	-	5	-	ns
		$V_{CC} = 4.5 \text{ V}$		5	-6	-	5	-	5	-	ns
		$V_{CC} = 6.0 \text{ V}$		5	-5	-	5	-	5	-	ns
f <sub>max</sub>	maximum	CP0 or CP1; see Figure 9									
	frequency	$V_{CC} = 2.0 \text{ V}$		6.0	23	-	4.8	-	4.0	-	MH
		$V_{CC} = 4.5 \text{ V}$		30	70	-	24	-	20	-	MH
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	77	-	-	-	-	-	MH
		$V_{CC} = 6.0 \text{ V}$		25	83	-	28	-	24	-	MHz
$C_{PD}$	power dissipation capacitance	$V_I = GND \text{ to } V_{CC};$ $V_{CC} = 5 \text{ V}; f_i = 1 \text{ MHz}$	[3]	-	35	-	-	-	-	-	pF
74HCT4	017										
t <sub>pd</sub>	propagation delay	CP0 to Qn; CP0 to $\overline{Q}$ 5-9; see Figure 10	[1]								
		$V_{CC} = 4.5 \text{ V}$		-	25	46	-	58	-	69	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	21	-	-	-	-	-	ns
		$\overline{\text{CP}}$ 1 to Qn; $\overline{\text{CP}}$ 1 to $\overline{\text{Q}}$ 5-9; see Figure 10									
		V <sub>CC</sub> = 4.5 V		-	25	50	-	63	-	75	ns
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$		-	21	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH to LOW propagation	MR to Q[1:9]; see Figure 10									
	delay	V <sub>CC</sub> = 4.5 V		-	22	46	-	58	-	69	ns
t <sub>PLH</sub>	LOW to HIGH propagation	MR to $\overline{Q}5-9$ , Q0; see Figure 10									
	delay	V <sub>CC</sub> = 4.5 V		-	20	46	-	58	-	69	ns

**Table 7. Dynamic characteristics** ...continued GND = 0 V;  $t_r = t_f = 6$  ns;  $C_L = 50$  pF; see Figure 11.

Symbol	Parameter	Conditions		25 °C		–40 °C t	o +85 °C	-40 °C to	+125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
t <sub>t</sub>	transition time	see Figure 10 [2]	•	•						
		$V_{CC} = 4.5 \text{ V}$	-	7	15	-	19	-	22	ns
t <sub>W</sub> pulse width		CP0 and CP1 (HIGH or LOW); see Figure 9								
		$V_{CC} = 4.5 \text{ V}$	16	7	-	20	-	24	-	ns
		MR (HIGH); see Figure 9								
		$V_{CC} = 4.5 \text{ V}$	16	4	-	20	-	24	-	ns
t <sub>su</sub>	set-up time	CP1 to CP0; CP0 to CP1; see Figure 8								
		$V_{CC} = 4.5 \text{ V}$	10	-3	-	13	-	15	-	ns
t <sub>h</sub>	hold time	CP1 to CP0; CP0 to CP1; see Figure 8								
		$V_{CC} = 4.5 \text{ V}$	10	6	-	13	-	15	-	ns
t <sub>rec</sub>	recovery time	MR to <u>CP</u> 0 and MR to <u>CP</u> 1; see <u>Figure 9</u>								
		$V_{CC} = 4.5 \text{ V}$	5	-5	-	5	-	5	-	ns
f <sub>max</sub>	maximum	CP0 or CP1; see Figure 9								
	frequency	$V_{CC} = 4.5 \text{ V}$	30	61	-	24	-	20	-	MHz
		$V_{CC} = 5.0 \text{ V};$ $C_L = 15 \text{ pF}$	-	67	-	-	-	-	-	MHz
$C_{PD}$	power dissipation capacitance	$V_{I} = GND \text{ to } V_{CC} - 1.5 \text{ V};$ [3] $V_{CC} = 5 \text{ V}; f_{i} = 1 \text{ MHz}$	-	36	-	-	-	-	-	pF

<sup>[1]</sup>  $t_{pd}$  is the same as  $t_{PHL}$  and  $t_{PLH}$ .

 $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \sum (C_L \times V_{CC}{}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_0$  = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

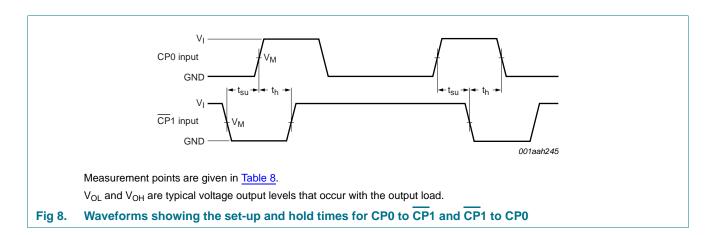
N = number of inputs switching;

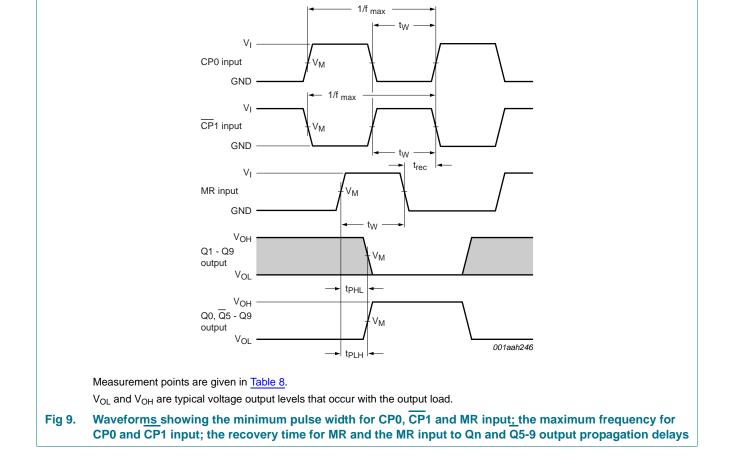
 $\sum (C_L \times V_{CC}{}^2 \times f_o)$  = sum of outputs.

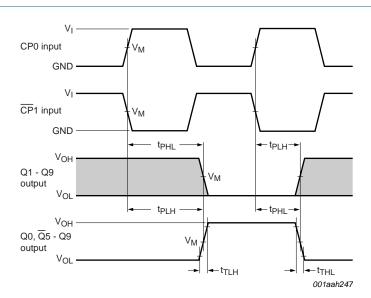
<sup>[2]</sup>  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .

<sup>[3]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W):

# 11. Waveforms







Measurement points are given in Table 8.

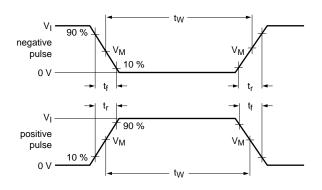
 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

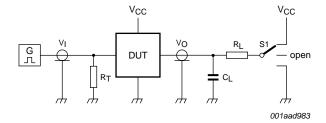
Conditions:  $\overline{\text{CP}}1 = \text{LOW}$  while CP0 is triggered on a LOW-to-HIGH transition and CP0 = HIGH, while  $\overline{\text{CP}}1$  is triggered on a HIGH-to-LOW transition.

Fig 10. Waveforms showing the propagation delays for CP0,  $\overline{\text{CP}}1$  to Qn,  $\overline{\text{Q}}5$ -9 outputs and the output transition times

Table 8. Measurement points

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC4017	0.5 × V <sub>CC</sub>	$0.5 \times V_{CC}$
74HCT4017	1.3 V	1.3 V





Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

R<sub>L</sub> = Load resistance.

S1 = Test selection switch.

Fig 11. Load circuitry for measuring switching times

Table 9. Test data

Туре	Input		Load	Load		S1 position			
	VI	t <sub>r</sub> , t <sub>f</sub>	C <sub>L</sub>	R <sub>L</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>		
74HC4017	$V_{CC}$	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>		
74HCT4017	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	$V_{CC}$		

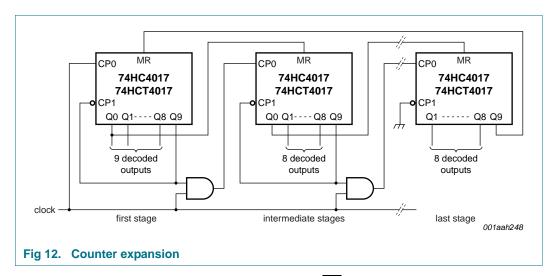
# 12. Application information

Some examples of applications for the 74HC4017; 74HCT4017 are:

- Decade counter with decimal decoding
- 1 out of n decoding counter (when cascaded)
- Sequential controller
- Timer

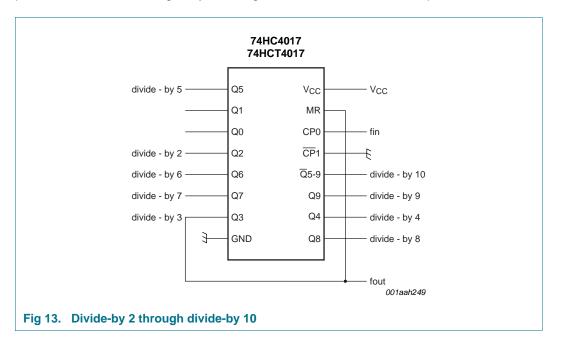
<u>Figure 12</u> shows a technique for extending the number of decoded output states for the 74HC4017; 74HCT4017. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).

74HC\_HCT4017



**Remark:** It is essential not to enable the counter on  $\overline{CP1}$  when CP0 is HIGH, or on CP0 when  $\overline{CP1}$  is LOW, as this would cause an extra count.

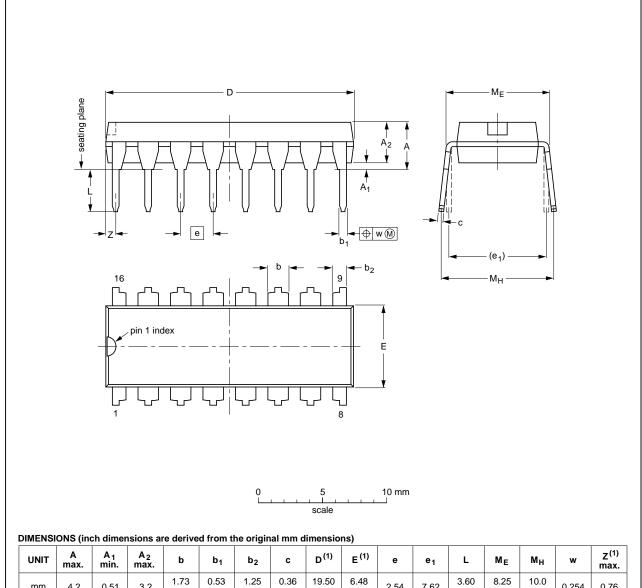
Figure 13 shows an example of a divide-by 2 through divide-by 10 circuit using one 74HC4017; 74HCT4017. Since the 74HC4017; 74HCT4017 has an asynchronous reset, the output pulse widths are narrow (minimum expected pulse width is 6 ns). The output pulse widths can be enlarged by inserting an RC network at the MR input.



# 13. Package outline

# DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	Мн	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

#### Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

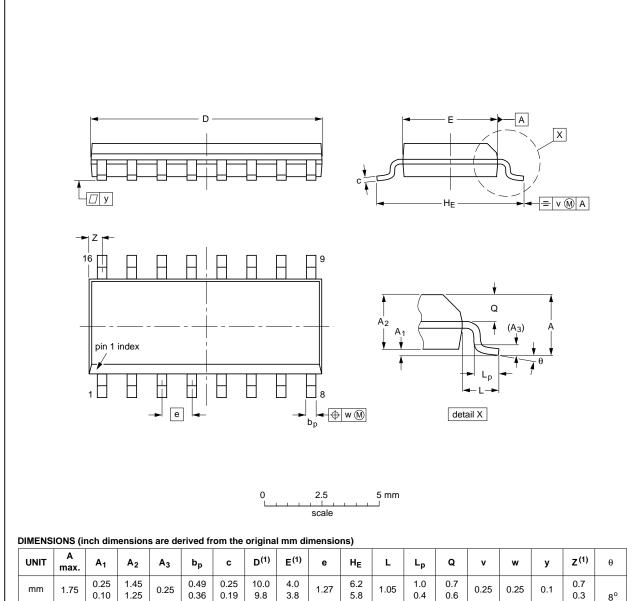
OUTLINE	REFERENCES EUROPEAN ISSUE							
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE		
SOT38-4						<del>95-01-14</del> 03-02-13		

Fig 14. Package outline SOT38-4 (DIP16)

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### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	ø	v	w	у	Z <sup>(1)</sup>	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01		0.0100 0.0075		0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

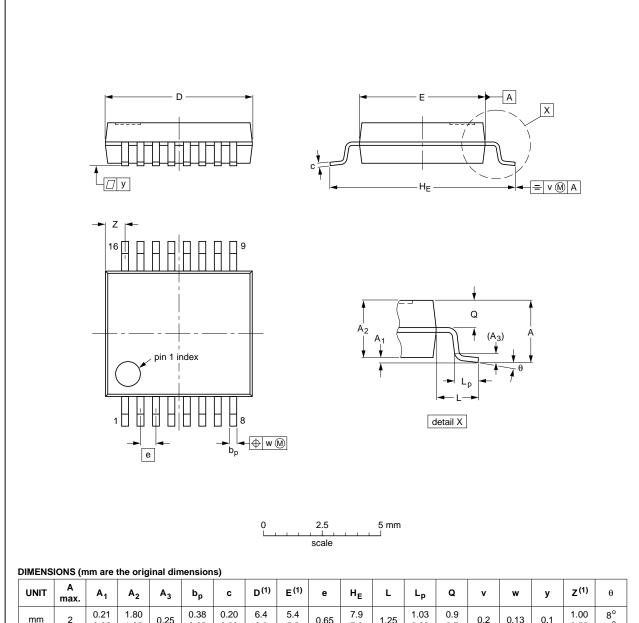
OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19	

Fig 15. Package outline SOT109-1 (SO16)

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SSOP16: plastic shrink small outline package; 16 leads; body width 5.3 mm

SOT338-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	b <sub>p</sub>	U	D <sup>(1)</sup>	E <sup>(1)</sup>	e	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.00 0.55	8° 0°

### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT338-1		MO-150			<del>99-12-27</del> 03-02-19	
				l.		

Fig 16. Package outline SOT338-1 (SSOP16)

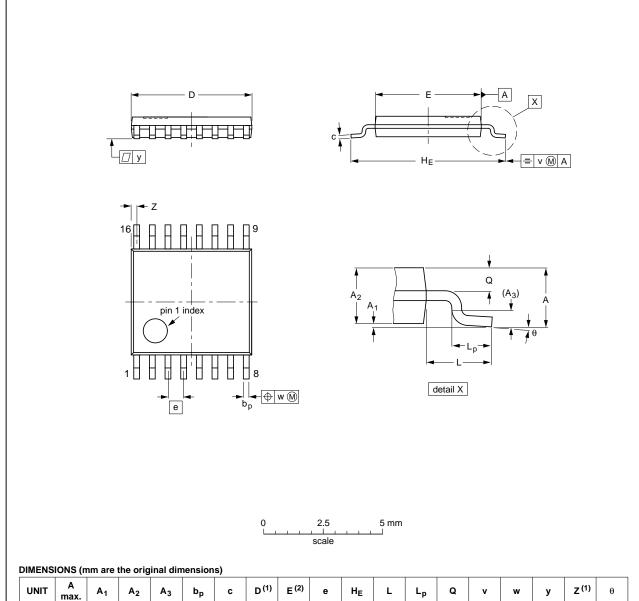
74HC\_HCT4017

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E (2)	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

#### Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	
501403-1		MO-153				<b>岁</b>	

Fig 17. Package outline SOT403-1 (TSSOP16)

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

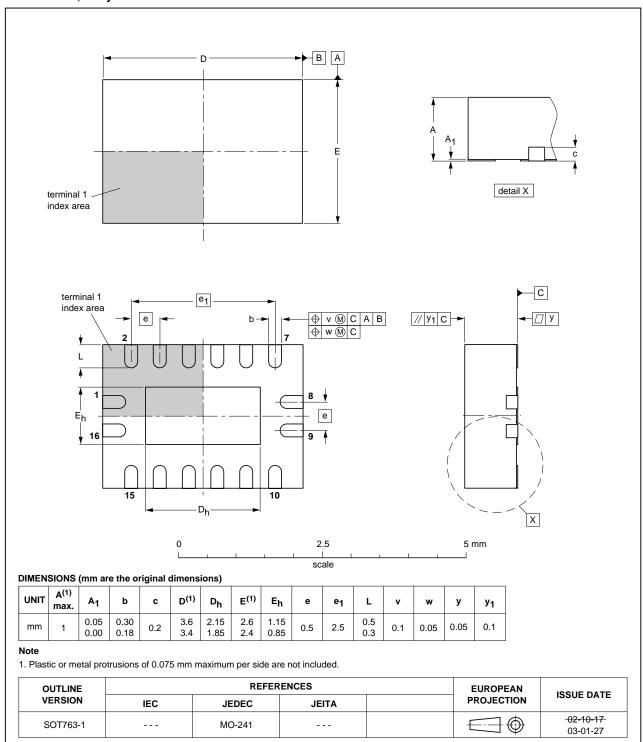


Fig 18. Package outline SOT763-1 (DHVQFN16)

74HC\_HCT4017

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# 14. Abbreviations

### Table 10. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 15. Revision history

# Table 11. Revision history

	-			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT4017 v.4	20131210	Product data sheet	-	74HC_HCT4017 v.3
Modifications:	<ul> <li>General de</li> </ul>	scription updated.		
74HC_HCT4017 v.3	20080108	Product data sheet	-	74HC_HCT4017_CNV v.2
Modifications:		of this data sheet has be of NXP Semiconductors.	en redesigned to co	mply with the new identity
	<ul> <li>Legal texts</li> </ul>	have been adapted to the	e new company nam	e where appropriate.
	• Section 3:	DHVQFN16 package add	ed.	
	• Section 7:	derating values added for	DHVQFN16 packag	le.
	Section 13	outline drawing added for	or DHVQFN16 packa	ge.
74HC_HCT4017_CNV v.2	19970829	Product specification	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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